



DATA SHEET

SEMICONDUCTOR

BCW70

General Purpose Transistors

PNP Silicon



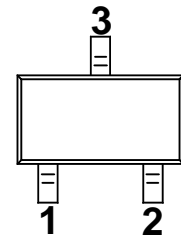
Features

Pb-Free Package is Available.

SOT-23 (TO-236AB)

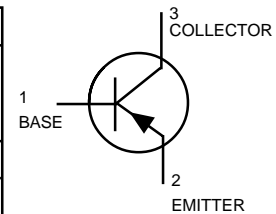
MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--------------------------------|-----------|-------|------|
| Collector-Emitter Voltage | V_{CEO} | -45 | Vdc |
| Emitter-Base Voltage | V_{EBO} | -5.0 | Vdc |
| Collector Current — Continuous | I_C | -100 | mAdc |



THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|-------------|---------------------------|
| Total Device Dissipation FR-5 Board, (1) $T_A = 25^\circ\text{C}$ | P_D | 225 | mW |
| Derate above 25°C | | 1.8 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 556 | $^\circ\text{C}/\text{W}$ |
| Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$ | P_D | 300 | mW |
| Derate above 25°C | | 2.4 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 417 | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |



DEVICE MARKING

BCW69 = H1; BCW70 = H2

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

OFF CHARACTERISTICS

| | | | | |
|--|---------------|------|------|-----------------|
| Collector-Emitter Breakdown Voltage ($I_C = -2.0 \text{ mAdc}, I_E = 0$) | $V_{(BR)CEO}$ | -45 | — | Vdc |
| Collector-Emitter Breakdown Voltage ($I_C = -100 \mu\text{Adc}, V_{EB} = 0$) | $V_{(BR)CES}$ | -50 | — | Vdc |
| Emitter-Base Breakdown Voltage ($I_E = -10 \mu\text{Adc}, I_C = 0$) | $V_{(BR)EBO}$ | -5.0 | — | Vdc |
| Collector Cutoff Current | I_{CEO} | — | -100 | nAdc |
| ($V_{CE} = -20 \text{ Vdc}, I_E = 0$) | | — | -10 | μAdc |
| ($V_{CE} = -20 \text{ Vdc}, I_E = 0, T_A = 100^\circ\text{C}$) | | — | -10 | μAdc |

1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

DEVICE CHARACTERISTICS

BCW70

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

| Characteristic | Symbol | Min | Max | Unit |
|--|---------------|------|-------|------|
| ON CHARACTERISTICS | | | | |
| DC Current Gain ($I_C = -2.0\text{ mA dc}$, $V_{CE} = -5.0\text{ Vdc}$) | h_{FE} | | | — |
| BCW69 | | 120 | 260 | |
| BCW70 | | 215 | 500 | |
| Collector–Emitter Saturation Voltage ($I_C = -10\text{ mA dc}$, $I_B = -0.5\text{ mA dc}$) | $V_{CE(sat)}$ | — | -0.3 | Vdc |
| Base–Emitter On Voltage ($I_C = -2.0\text{ mA dc}$, $V_{CE} = -5.0\text{ Vdc}$) | $V_{BE(on)}$ | -0.6 | -0.75 | Vdc |

SMALL–SIGNAL CHARACTERISTICS

| | | | | |
|---|-----------|---|-----|----|
| Output Capacitance ($I_E = 0\text{ V}$, $V_{CB} = -10\text{ Vdc}$, $f = 1.0\text{ MHz}$) | C_{obo} | — | 7.0 | pF |
| Noise Figure ($V_{CE} = -5.0\text{ Vdc}$, $I_C = -0.2\text{ mA dc}$, $R_S = 2.0\text{ k}\Omega$, $f = 1.0\text{ kHz}$, $BW = 200\text{ Hz}$) | N_F | — | 10 | dB |

Ordering Information

| Device | Marking | Shipping |
|--------|---------|----------------|
| BCW69 | H1 | 3000/Tape&Reel |
| BCW70 | H2 | 3000/Tape&Reel |

DEVICE CHARACTERISTICS

BCW70

TYPICAL NOISE CHARACTERISTICS

($V_{CE} = -5.0$ Vdc, $T_A = 25^\circ\text{C}$)

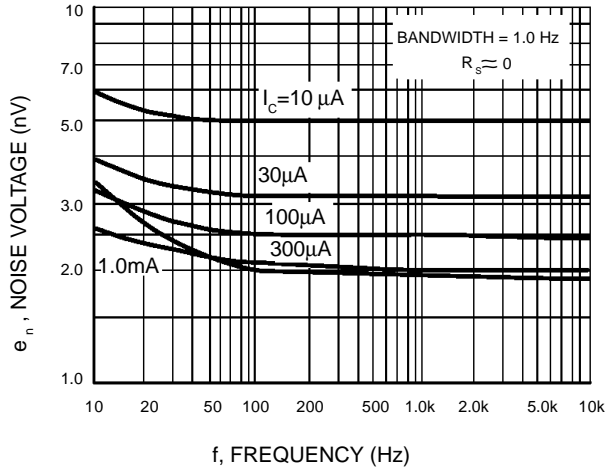


Figure 1. Noise Voltage

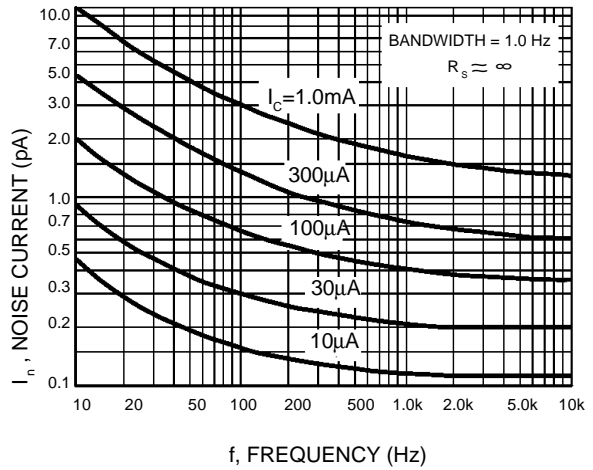


Figure 2. Noise Current

NOISE FIGURE CONTOURS

($V_{CE} = -5.0$ Vdc, $T_A = 25^\circ\text{C}$)

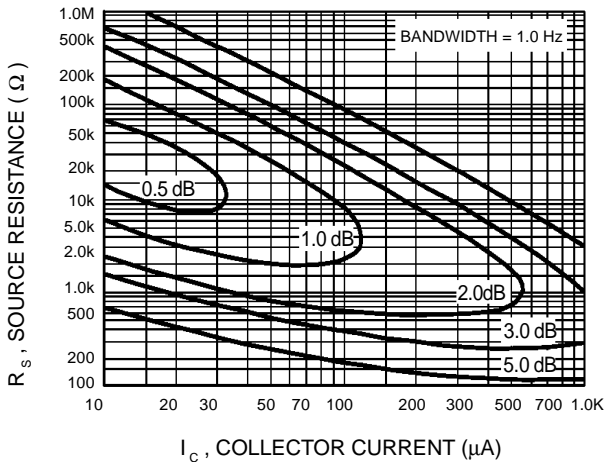


Figure 3. Narrow Band, 100 Hz

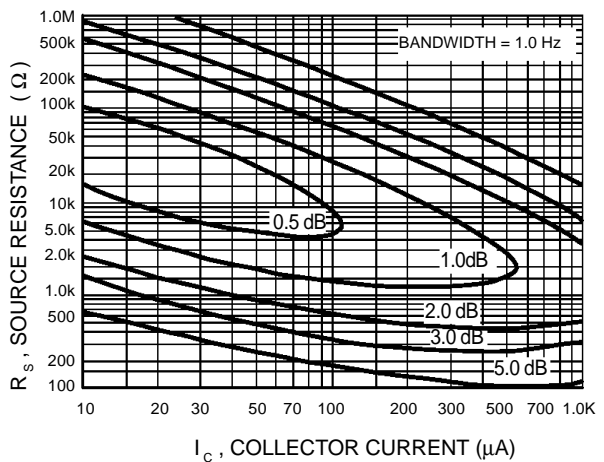


Figure 4. Narrow Band, 1.0 kHz

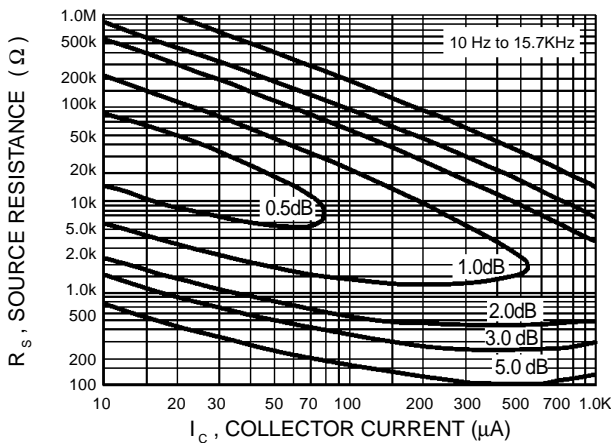


Figure 5. Wideband

Noise Figure is Defined as:

$$NF = 20 \log_{10} \left(\frac{e_n^2 + 4KTR_s + I_n^2 R_s^2}{4KTR_s} \right)^{1/2}$$

- e_n = Noise Voltage of the Transistor referred to the input. (Figure 3)
- I_n = Noise Current of the Transistor referred to the input. (Figure 4)
- K = Boltzman's Constant (1.38×10^{-23} j/°K)
- T = Temperature of the Source Resistance (°K)
- R_s = Source Resistance (Ω)

DEVICE CHARACTERISTICS

BCW70

TYPICAL STATIC CHARACTERISTICS

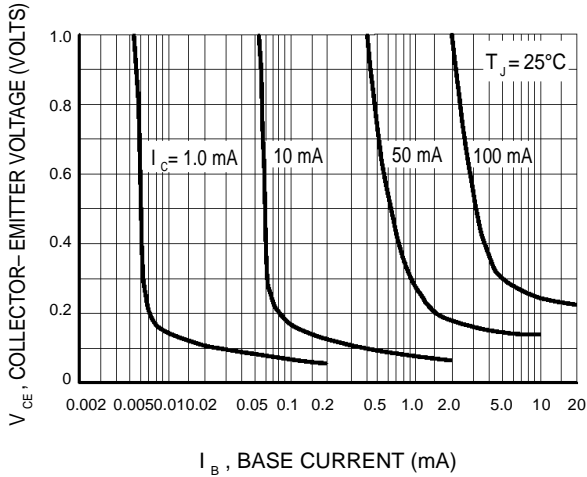


Figure 6. Collector Saturation Region

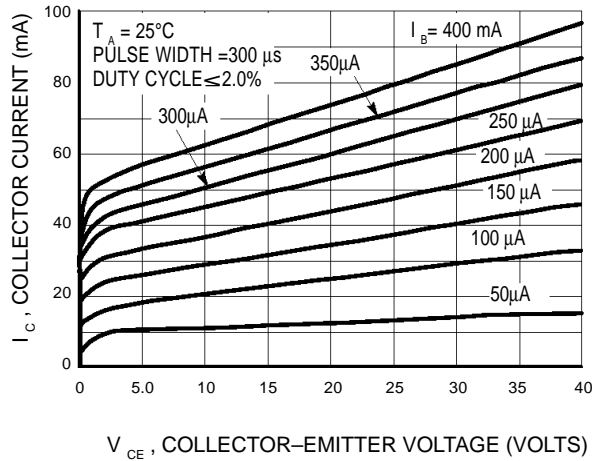


Figure 7. Collector Characteristics

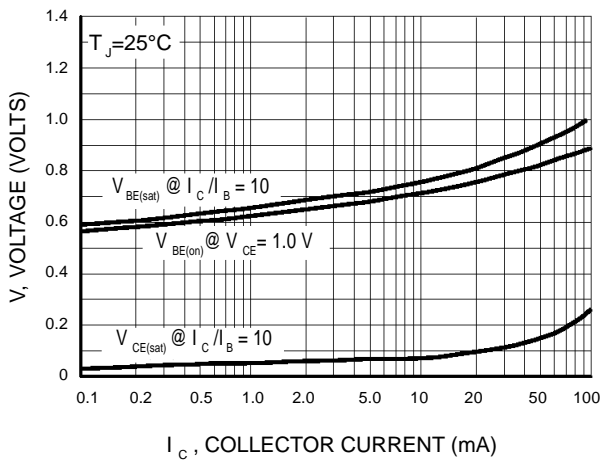


Figure 10. "On" Voltages

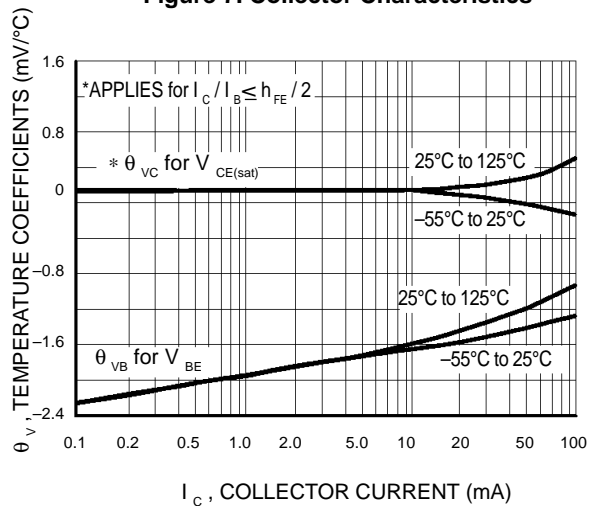
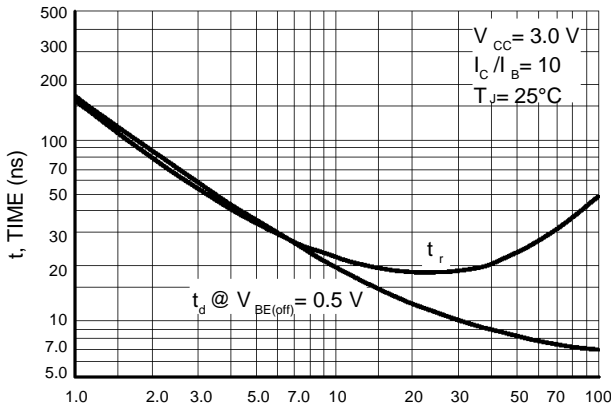


Figure 11. Temperature Coefficients

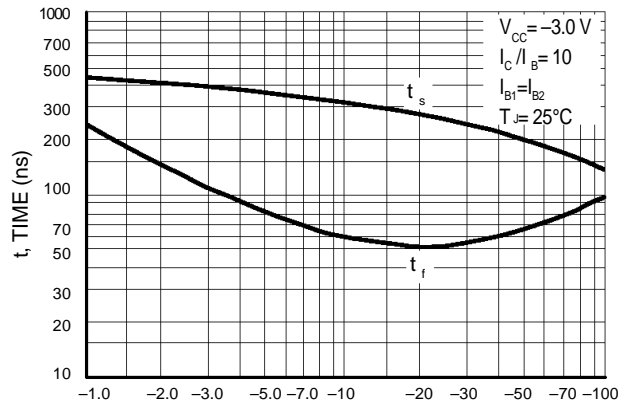
DEVICE CHARACTERISTICS

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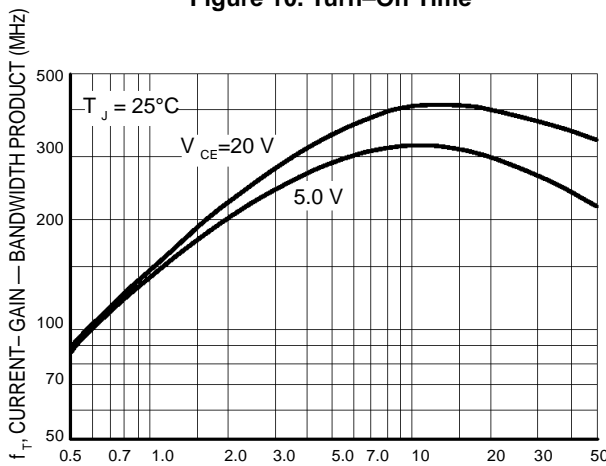
TYPICAL DYNAMIC CHARACTERISTICS



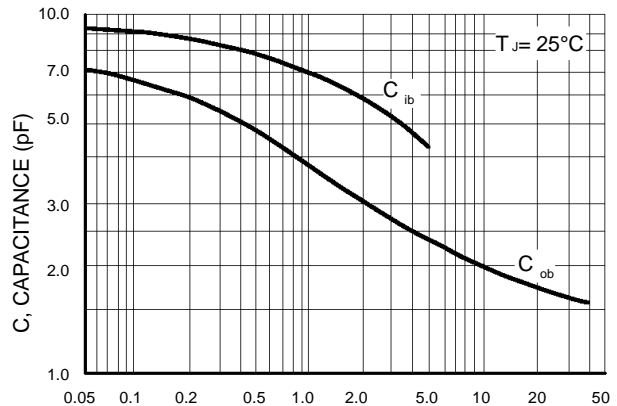
I_C , COLLECTOR CURRENT (mA)
Figure 10. Turn-On Time



I_C , COLLECTOR CURRENT (mA)
Figure 11. Turn-Off Time



I_C , COLLECTOR CURRENT (mA)
Figure 12. Current-Gain — Bandwidth Product



V_R , REVERSE VOLTAGE (VOLTS)
Figure 13. Capacitance

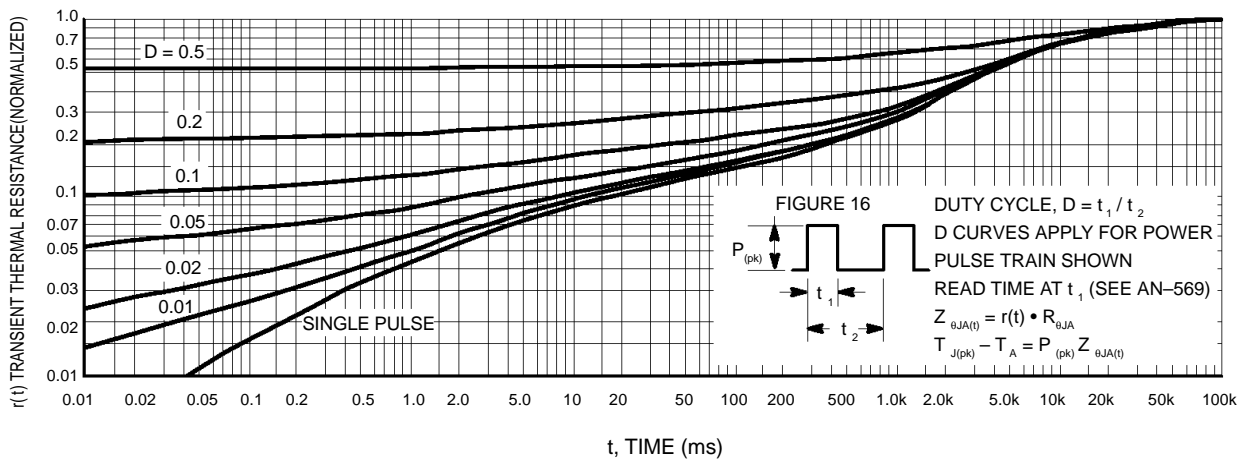


Figure 14. Thermal Response

DEVICE CHARACTERISTICS

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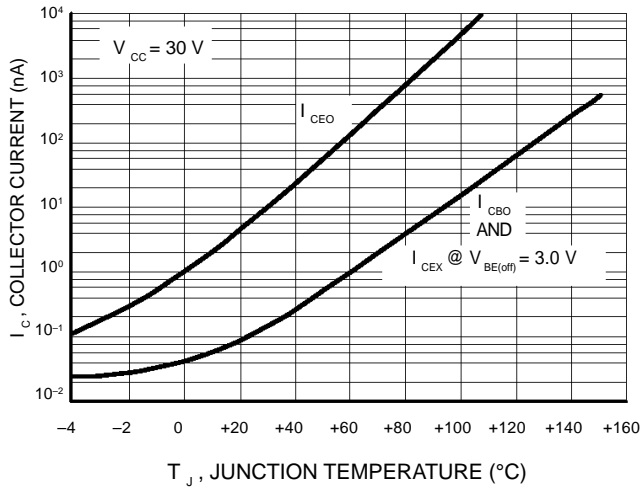


Figure 15. Typical Collector Leakage Current

DESIGN NOTE: USE OF THERMAL RESPONSE DATA

A train of periodical power pulses can be represented by the model as shown in Figure 16. Using the model and the device thermal response the normalized effective transient thermal resistance of Figure 14 was calculated for various duty cycles.

To find $Z_{\theta JA(t)}$, multiply the value obtained from Figure 14 by the steady state value $R_{\theta JA}$.

Example:

Dissipating 2.0 watts peak under the following conditions:

$t_1 = 1.0 \text{ ms}$, $t_2 = 5.0 \text{ ms}$. ($D = 0.2$)

Using Figure 14 at a pulse width of 1.0 ms and $D = 0.2$, the reading of $r(t)$ is 0.22.

The peak rise in junction temperature is therefore

$$\Delta T = r(t) \times P_{(pk)} \times R_{\theta JA} = 0.22 \times 2.0 \times 200 = 88^{\circ}\text{C}.$$

For more information, see AN-569.

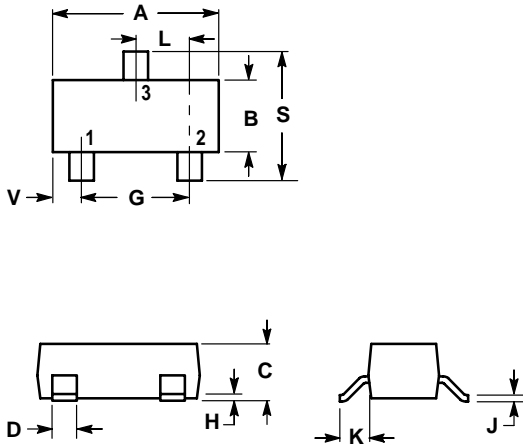
PACKAGE OUTLINE & DIMENSIONS

BCW70

SOT-23

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
2. CONTROLLING DIMENSION: INCH.



| DIM | INCHES | | MILLIMETERS | |
|-----|--------|--------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.1102 | 0.1197 | 2.80 | 3.04 |
| B | 0.0472 | 0.0551 | 1.20 | 1.40 |
| C | 0.0350 | 0.0440 | 0.89 | 1.11 |
| D | 0.0150 | 0.0200 | 0.37 | 0.50 |
| G | 0.0701 | 0.0807 | 1.78 | 2.04 |
| H | 0.0005 | 0.0040 | 0.013 | 0.100 |
| J | 0.0034 | 0.0070 | 0.085 | 0.177 |
| K | 0.0140 | 0.0285 | 0.35 | 0.69 |
| L | 0.0350 | 0.0401 | 0.89 | 1.02 |
| S | 0.0830 | 0.1039 | 2.10 | 2.64 |
| V | 0.0177 | 0.0236 | 0.45 | 0.60 |

